NSN 5961-00-907-0593



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-00-907-0593 **Inclosure Material:** Metal **Overall Length:** 1.540 inches **Overall Height:** 0.310 inches **Overall Width:** 1.010 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: T0-3 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 breakdown voltage, collector-to-base, emitter open **Current Rating Per Characteristic:** 20.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 90.0 watts small-signal input power, common-collector preset **Transfer Ratio:** 50.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 70.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure:**

No

Demilitarization:

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